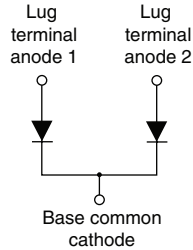


## HEXFRED® Ultrafast Soft Recovery Diode, 320 A



TO-244


**FEATURES**

- Very low  $Q_{rr}$  and  $t_{rr}$
- Lead (Pb)-free
- Designed and qualified for industrial level


**RoHS  
COMPLIANT**
**BENEFITS**

- Reduced RFI and EMI
- Reduced snubbing

**DESCRIPTION**

HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

**PRODUCT SUMMARY**

$I_{F(AV)}$	320 A
$V_R$	400 V
$I_{F(DC)}$ at $T_C$	255 A at 85 °C

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	$V_R$		400	V
Continuous forward current	$I_F$	$T_C = 25\text{ °C}$	420	A
		$T_C = 85\text{ °C}$	255	
		$T_C = 115\text{ °C}$	160	
Single pulse forward current	$I_{FSM}$	Limited by junction temperature	1200	
Non-repetitive avalanche energy	$E_{AS}$	$L = 100\ \mu\text{H}$ , duty cycle limited by maximum $T_J$	1.4	mJ
Maximum power dissipation	$P_D$	$T_C = 25\text{ °C}$	625	W
		$T_C = 100\text{ °C}$	250	
Operating junction and storage temperature range	$T_J, T_{Stg}$		- 55 to 150	°C

**ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$  unless otherwise specified)**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	$V_{BR}$	$I_R = 100\ \mu\text{A}$	400	-	-	V	
Maximum forward voltage	$V_{FM}$	$I_F = 160\text{ A}$	-	1.10	1.35		
		$I_F = 320\text{ A}$	-	1.30	1.54		
		$I_F = 160\text{ A}, T_J = 125\text{ °C}$	-	1.00	1.20		
Maximum reverse leakage current	$I_{RM}$	$T_J = 125\text{ °C}, V_R = 400\text{ V}$	See fig. 2	-	0.9	3	mA
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	See fig. 3	-	370	500	pF
Series inductance	$L_S$	From top of terminal hole to mounting plane	-	5.0	-	nH	

DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5	t <sub>rr</sub>	I <sub>F</sub> = 1.0 A, dI <sub>F</sub> /dt = 200 A/μs, V <sub>R</sub> = 30 V	-	45	-	ns
		T <sub>J</sub> = 25 °C	-	90	140	
		T <sub>J</sub> = 125 °C	-	290	440	
Peak recovery current See fig. 6	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	-	8.7	20	A
		T <sub>J</sub> = 125 °C	-	18	30	
Reverse recovery charge See fig. 7	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	-	420	1100	nC
		T <sub>J</sub> = 125 °C	-	2600	7000	
Peak rate of recovery current See fig. 8	dI <sub>(rec)</sub> M/dt	T <sub>J</sub> = 25 °C	-	300	-	A/μs
		T <sub>J</sub> = 125 °C	-	280	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>	- 55	-	150	°C	
Thermal resistance, junction to case	per leg	-	-	0.19	°C/W K/W	
	per module	-	-	0.095		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	-	0.10	-		
Weight		-	68	-	g	
		-	2.4	-	oz.	
Mounting torque	(1)	30 (3.4)	-	40 (4.6)	N · m (lbf · in)	
	center hole	12 (1.4)	-	18 (2.1)		
Terminal torque		30 (3.4)	-	40 (4.6)		
Vertical pull		-	-	80	lbf · in	
2" lever pull		-	-	35		

**Note**

(1) Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 to 10 lbf · in steps until desired or maximum torque limits are reached.



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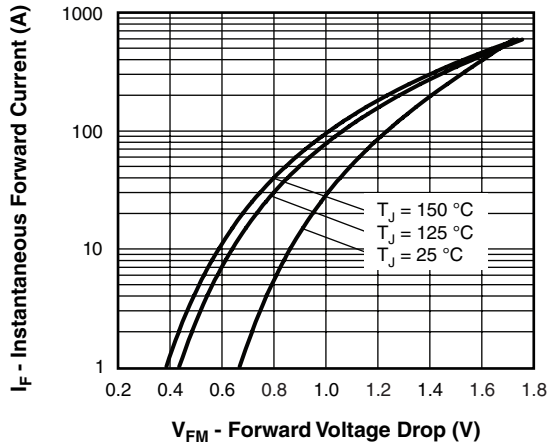


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

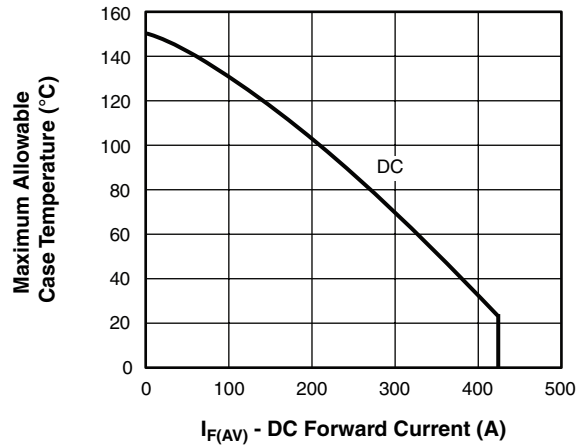


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

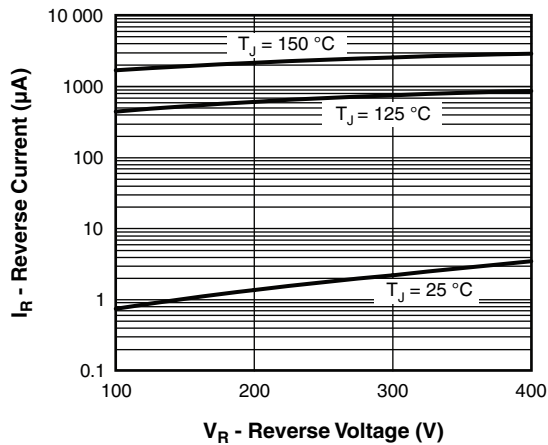


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

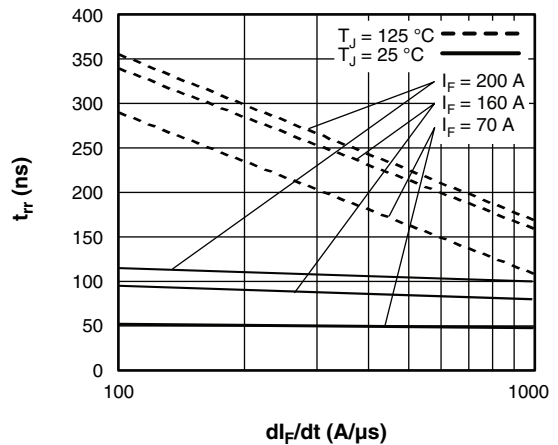


Fig. 5 - Typical Reverse Recovery Time vs.  $di_F/dt$  (Per Leg)

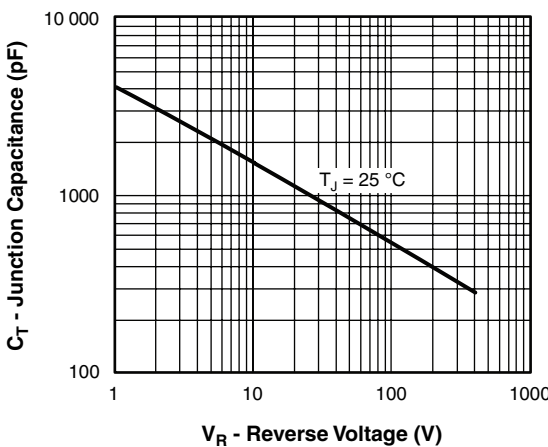


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

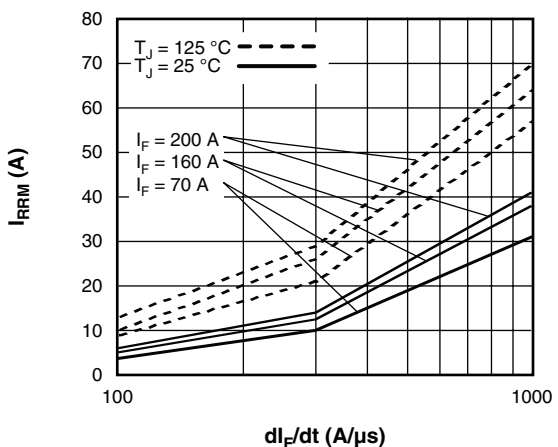


Fig. 6 - Typical Recovery Current vs.  $di_F/dt$  (Per Leg)

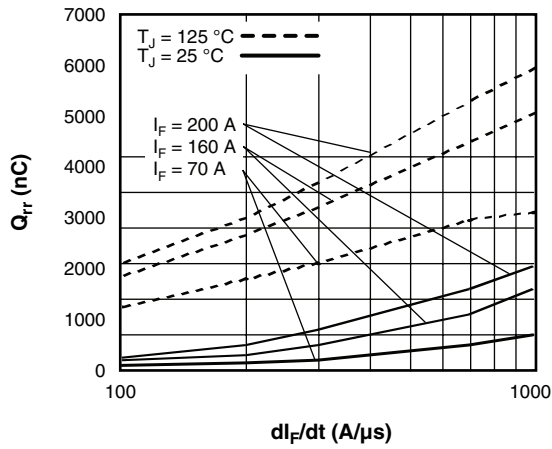


Fig. 7 - Typical Stored Charge vs.  $di_F/dt$  (Per Leg)

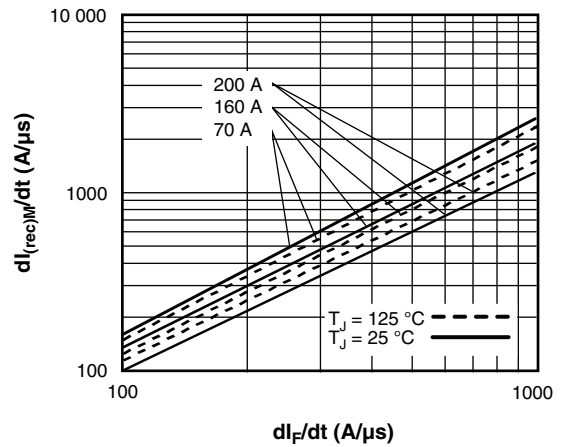


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $di_F/dt$  (Per Leg)

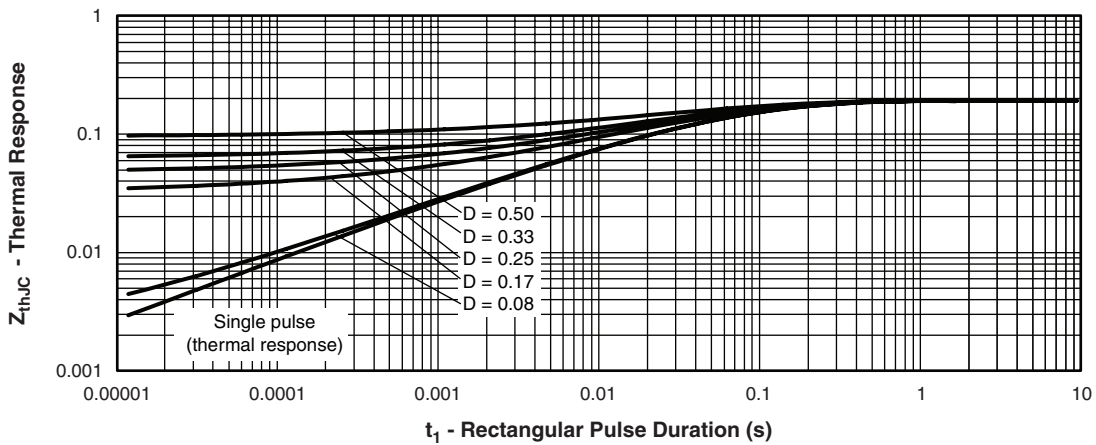


Fig. 9 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

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**Diode, 320 A**

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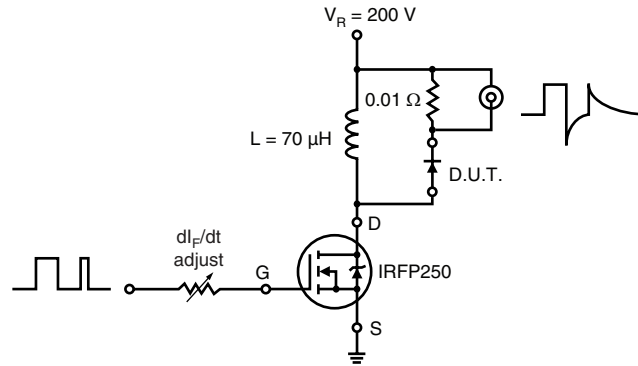
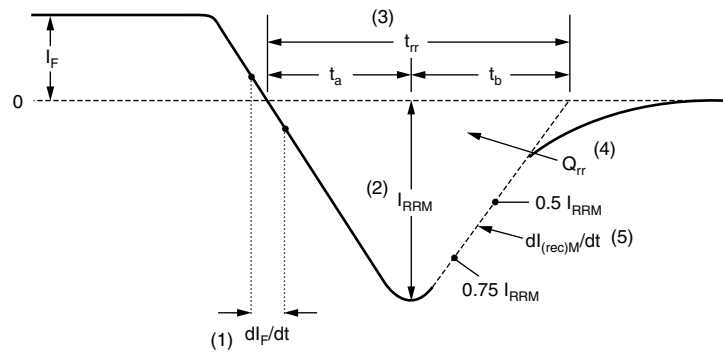


Fig. 10 - Reverse Recovery Parameter Test Circuit


 (1)  $di_F/dt$  - rate of change of current through zero crossing

 (2)  $I_{RRM}$  - peak reverse recovery current

 (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

 (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$ 

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

 (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 11 - Reverse Recovery Waveform and Definitions

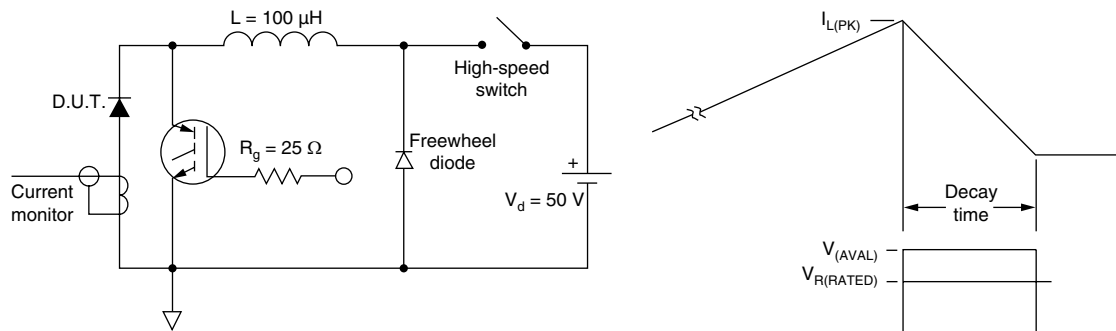


Fig. 12 - Avalanche Test Circuit and Waveforms

# HFA320NJ40CPbF

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## ORDERING INFORMATION TABLE

Device code	<b>HFA</b>	<b>320</b>	<b>NJ</b>	<b>40</b>	<b>C</b>	<b>PbF</b>
	①	②	③	④	⑤	⑥
	<b>1</b>	-	HEXFRED® family, electron irradiated			
	<b>2</b>	-	Average current rating			
	<b>3</b>	-	NJ = TO-244			
	<b>4</b>	-	Voltage rating (400 V)			
	<b>5</b>	-	C = Common cathode			
	<b>6</b>	-	Lead (Pb)-free			

### LINKS TO RELATED DOCUMENTS

Dimensions	<a href="http://www.vishay.com/doc?95021">http://www.vishay.com/doc?95021</a>
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